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## DATASHEET

# Silicon Planar PIN Photodiode PD70-01C/TR10



#### **Features**

- High sensitivity
- Low capacitance
- Short switching time
- Wide temperature range
- Small package
- Pb free
- The product itself will remain within RoHS compliant version.

## Descriptions

• The PD70-01C/TR10 is high sensitivity, fast switching times, low capacitance, ompact 2 size, and lack of measurable degradation make it suitable for diverse applications, such as TV and appliance remote control, IR sound transmission, video recorders, and measurement and ontrol.

## **Applications**

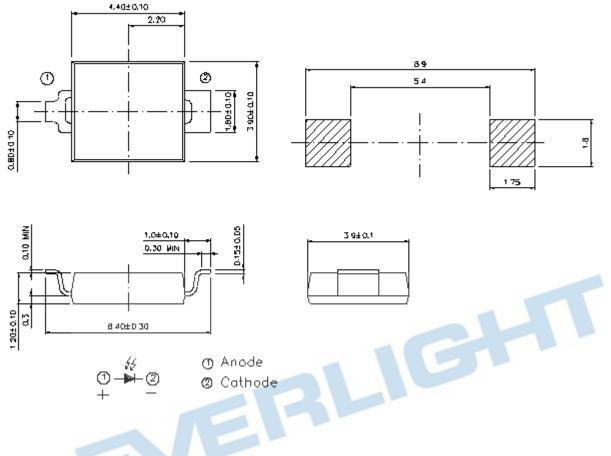
- High speed photo detector
- Copier
- Elevator

#### **Device Selection Guide**

Part Category	Chip Material	Lens Color
PD	Silicon	Water clear

**EVERLIGHT** 

#### **Package Dimensions**



- Notes: 1.All dimensions are in millimeters
  - 2.Tolerances unless dimensions ±0.1mm

## Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Units
Reverse Voltage	$V_{R}$	32	V
Operating Temperature	T <sub>opr</sub>	-25 ~ +85	°C
Storage Temperature	T <sub>stg</sub>	-40 ~ +85	°C
Soldering Temperature *1	T <sub>sol</sub>	260	°C
Power Dissipation at (or below) 25°C Free Air Temperature	P <sub>d</sub>	150	mW

**Notes:** \*1: Soldering time  $\leq$  5 seconds.

## **Electro-Optical Characteristics (Ta=25°C)**

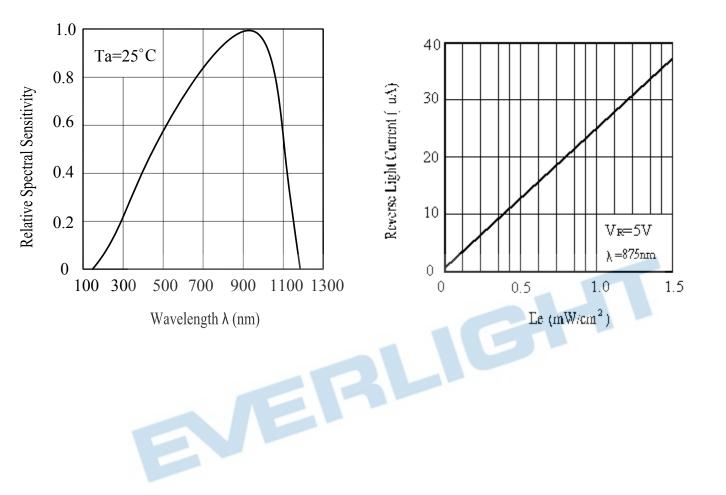
Parameter	Symbol	Condition	Min.	Тур.	Max.	Units
Rang of Spectral Bandwidth	$\lambda_{0.5}$		400		1100	nm
Wavelength of Peak Sensitivity	$\lambda_{P}$			940		nm
Short- Circuit Current	I <sub>SC</sub>	Ee=1mW/cm <sup>2</sup> λp=875nm	1	35		μA
Reverse Light Current	IL I	Ee=1mW/cm <sup>2</sup> λp=875nm V <sub>R</sub> =5V	17	25		μA
Reverse Dark Current	ID	Ee=0mW/cm <sup>2</sup> V <sub>R</sub> =10V		5	30	nA
Reverse Breakdown Voltage	$V_{BR}$	Ee=0mW/cm <sup>2</sup> I <sub>R</sub> =100µA	32	170		V



#### **Typical Electro-Optical Characteristics Curves**

Fig.1 Spectral Sensitivity

Fig. 2 Reverse Light Current vs. Ee



## **Precautions For Use**

1. Over-current-proof

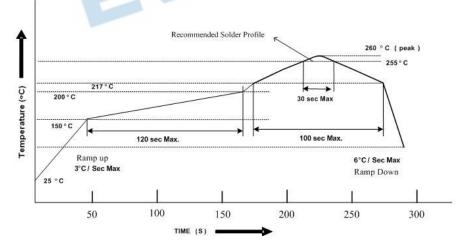
Customer must apply resistors for protection, otherwise slight voltage shift will cause big

current change ( Burn out will happen ).

- 2. Storage
  - 2.1 Do not open moisture proof bag before the products are ready to use.
  - 2.2 Before opening the package, the Photodiode should be kept at  $10^{\circ}$ C ~ $30^{\circ}$ C and 90%RH or less.
  - 2.3 The Photodiode suggested be used within one year.
  - 2.4 After opening the package, the devices must be stored at 10°C~30°C and ≤ 60%RH, and used within 168 hours (floor life). If unused Photodiode remain, it should be stored in moisture proof packages.
  - 2.5 If the moisture absorbent material (desiccant material) has faded or unopened bag has exceeded the shelf life or devices (out of bag) have exceeded the floor life, baking treatment is required.
  - 2.6 If baking is required, refer to IPC/JEDEC J-STD-033 for bake procedure or recommend the following conditions:

96 hours at 60°C ± 5°C and < 5 % RH (reeled/tubed/loose units)

- 3. Soldering Condition
  - 3.1 Pb-free solder temperature profile



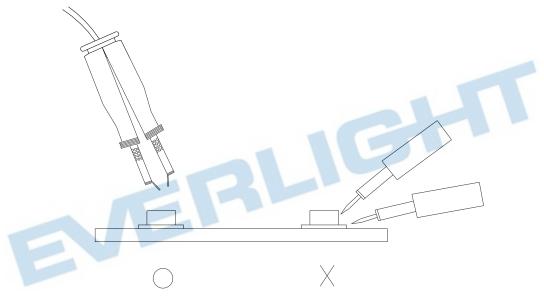
- 3.2 Reflow soldering should not be done more than two times.
- 3.3 When soldering, do not put stress on the Photodiode during heating.
- 3.4 After soldering, do not warp the circuit board.

4. Soldering Iron

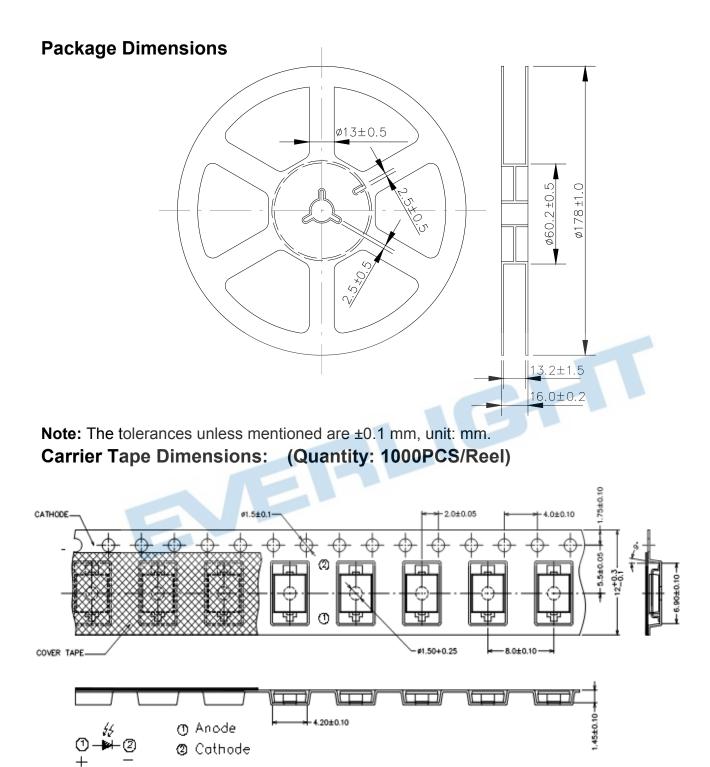
Each terminal is to go to the tip of soldering iron temperature less than  $350^{\circ}$  for 3 seconds within once in less than the soldering iron capacity 25W. Leave two seconds and more intervals, and do soldering of each terminal. Be careful because the damage of the product is often started at the time of the hand solder.

#### 5. Repairing

Repair should not be done after the Photodiode have been soldered. When repairing is unavoidable, a double-head soldering iron should be used (as below figure). It should be confirmed beforehand whether the characteristics of the Photodiode will or will not be damaged by repairing.



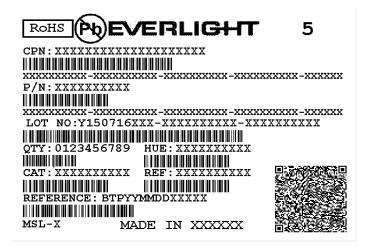




Note: The tolerances unless mentioned are ±0.1 mm, unit: mm.

Ver.: Release Date: Confidential Level: 狀態:

## **Label Form Specification**



CPN: Customer's Production Number P/N : Production Number QTY: Packing Quantity CAT: Ranks HUE: Peak Wavelength REF: Reference LOT No: Lot Number

#### Notes

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
- 3. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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